16-bit Microcontrollers

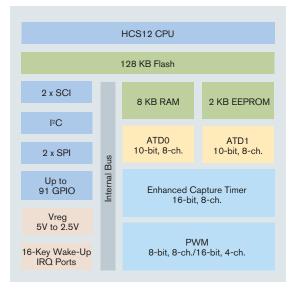
MC9S12A128

Target Applications

- > Instrumentation
- > Energy management
- > Industrial control
- > Robotics
- > Safety equipment
- > Security

Overview

Freescale Semiconductor's MC9S12A128 Flash microcontroller (MCU) is the next generation of the highly successful 68HC12 architecture. Using Freescale's industry-leading 0.25 µs Flash, the A128 is part of a pin-compatible family that scales from 32 KB to 512 KB of Flash memory. The MC9S12A128 provides an upward migration path from Freescale's 68HC08, 68HC11 and 68HC12 architectures for applications that need larger memory, more peripherals and higher performance.



High-Performance 16-bit HCS12 CPU Core > 25 MHz bus operation at 5V for 40 ns minimum instruction cycle time > Opcode compatible with the 68HC11 and 68HC12 > C-optimized architecture produces extremely compact code > C-optimized architecture produces extremely compact code On-Chip Debug Interface > Real-time in-circuit emulation and debug without expensive and cumbersome box emulators > On-chip breakpoints > Read/write memory and registers while running at full speed Integrated Third-Generation Flash Memory > In-application reprogrammable > Self-timed, fast programming > Efficient end-of-line programming • Fast Flash page erase—20 ms (512 bytes) > Total program time for 128 KB code is less than five seconds • Can program 16 bits in 20 μs while in burst mode > Reduces production programming cost through ultra-fast programming > 5V Flash program/erase/read > No external high voltage or charge pump required > Flash granularity—512 byte Flash erase/2 byte Flash program > Virtual EEPROM implementation, Flash array usable for EE extension > Two independently programmable Flash arrays > Can erase one array while executing code from another
> 25 MHz bus operation at 5V for 40 ns minimum instruction cycle time > Opcode compatible with the 68HC11 and 68HC12 > C-optimized architecture produces extremely compact code On-Chip Debug Interface > Dedicated serial debug interface > Real-time in-circuit emulation and debug without expensive and cumbersome box emulators > Read/write memory and registers while running at full speed > Flexibility to change code in the field > Self-timed, fast programming > Fast Flash page erase—20 ms (512 bytes) > Total program time for 128 KB code is less than five seconds > Reduces production programming > Reduces production programming > Reduces production programming > No external high voltage or charge pump required > No external high voltage or charge pump required > Virtual EEPROM implementation, Flash array usable for EE extension > Can erase one array while executing code from another > Can erase one array while executing code > Can erase one array while > Can erase one erray while executing code > Can
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from another
> Flexible block protection and security
2 KB Integrated EEPROM
> Flexible protection scheme for protection against accidental program or erase 2 bytes at a time for calibration, security,
> EEPROM can be programmed in 46 µs
10-bit Analog-to-Digital Converter (ADC)
> Two, 8-channel ADCs > Fast, easy conversion from analog inputs
 7 μs, 10-bit single conversion time, scan mode available like position sensors, analog meters and photovoltaic cells to digital values for CPU processing
> Can effectively have 3.5 μs conversion time by sampling same signal with both ADCs



Features	Benefits
Clock Generation Module with Phase-Lock Loop	(PLL)
> Clock monitor with limp home mode in case of no external clock	> Reliable, robust operation> Provides high performance using low-cost
> Programmable clock frequency with 1024 options ranging from divide by 16 to multiply	reference crystals
by 64 form base oscillator	> Reduces generated noise
> Real-time interrupt	> Reduces power consumption
> Watchdog	> Easily able to implement real-time clock
Enhanced Capture Timer	
> 8-channel, 16-bit with input capture, output compare and pulse accumulator	> Flexible, programmable timer system
> 16-bit modulus down counter	
8-bit or 16-bit Pulse-Wide Modulation (PWM)	
> 8-channel, 8-bit or 4-channel, 16-bit PWM	> Efficiently implement motor control, battery
> PWM supports center-aligned operation	charging or digital-to-analog (DAC) functions
Two Serial Communications Interfaces	
> 8192 prescaler option	 Asynchronous communication between the MCU and a terminal, computer or a network of MCUs
Two Serial Peripheral Interfaces	
> 256 clock rate options	> High-speed synchronous communication between multiple MCUs or between MCU and serial peripherals
Inter IC (I²C) Bus	
	> Provides a simple, efficient method of data exchange between devices
	> Minimizes the need for large numbers of connections between devices and eliminates the need for an address decoder
Up to 91 Input/Output (I/O) Lines	
> Programmable pull-ups/pull-downs	> Reduce system cost
> Dual drive capability	> Able to tailor application for minimum EMC or high current loads

Data Sheets	
S12DT128DGV2	MC9S12A128 Device Guide
S12DT128PIMV1	MC9S12A128 Port Integration Module Block Guide
S12ATD10B8CV2	HCS12 10-bit 8-channel Analog to Digital Block Guide
S12BDMV4	HCS12 Background Debug (BDM) Block Guide
S12BKVD1	HCS12 Breakpoint (BKP) Block Guide
S12CPUV2	HCS12 CPU Reference Manual
S12CRGV3	HCS12 Clock Reset Generator Block Guide
S12EETS2KV1	HCS12 2K EEPROM Block Guide
S12FTS128KV1	HCS12 128K Flash Block Guide
S12IICV2	HCS12 I ² C Block Guide
S12INTV1	HCS12 Interrupt (INT) Block Guide
S12MEBIV3	HCS12 Multiplexed External Bus Interface (MEBI) Block Guide
S12MMCV4	HCS12 Module Mapping Control (MMC) Block Guide
S12PWM8B8CV1	HCS12 8-bit 8-channel Pulse-Width Modulator Block Guide
S12SCIV2	HCS12 Serial Communications Interface Block Guide
S12SPIV2	HCS12 Serial Peripheral Interface Block Guide
S12TIM16B8CV1	HCS12 16-bit 8-channel Timer Block Guide
S12VREGV1	HCS12 Voltage Regulator Block Guide

Cost-Effective Development Tools

For more information on development tools, please refer to the Freescale Development Tool Selector Guide (SG1011).

M68KIT912DP256 \$495

Evaluation kit for development and evaluation of HCS12 application

code that includes the M68EVB912DP256 and USBMULTILINKBDM

M68CYCLONEPRO \$499

HC08/HCS08/HC12/HCS12 stand-alone Flash programmer or in-circuit emulator, debugger, Flash programmer; USB, serial or Ethernet interface options

USBMULTILINKBDM Universal HCS08/HCS12 in-circuit emulator, debugger, and Flash programmer; USB PC interface

CWX-H12-SE

Free

Package Options

Part Number

MC9S12A128CFU

MC9S12A128CPV

CodeWarrior™ Special Edition for HCS12 MCUs; includes integrated development environment (IDE), linker, debugger, unlimited assembler, Processor Expert™ auto-code generator, full-chip simulation and limited C compiler

Application Notes and Engineering Bulletins

AN2206	Security and Protection on the HCS12 Family
AN2213	Using Cosmic Software's M68HC12 Compiler for MC9S12DP256 Software Development
AN2216	MC9S12DP256 Software Development Using Metrowerks CodeWarrior™
AN2250	Audio Reproduction on HCS12 Microcontrollers
EB386	HCS12 D-Family Compatibility

FU

80-Lead LQFP

Package Temp. Range 80 QFP -40°C to +85°C 112 LQFP -40°C to +85°C 112-Lead LQFP

Learn More: For more information about Freescale products, please visit www.freescale.com.

